## NSN 5961-01-326-0627

A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-326-0627 **Inclosure Material:** Ceramic **Overall Length:** 0.555 inches **Overall Diameter:** 1.625 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 repetitive peak off-state voltage and 1200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 470.00 amperes forward current, total rms horsepower metric and 300.00 amperes drain current universal and 150.00 milliamperes drain current absolute **Terminal Type And Quantity:** 2 case and 1 pin and 1 quick disconnect, male Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: